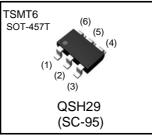
Parameter	Value
V <sub>CEO</sub>	60V
Ι <sub>C</sub>	500mA
R	10k $\Omega$

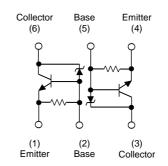
#### Features

- 1) Built-In Biasing Resistors
- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see inner circuit).
- The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of completely eliminating parasitic effects.
- 4) Lead Free/RoHS Compliant.

#### Outline



#### Inner circuit



#### Application

Switching circuit, Inverter circuit, Interface circuit, Driver circuit

#### Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
QSH29	TSMT6	2928	TR	180	8	3,000	H29

#### ●Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Values	Unit
Collector-base voltage	V <sub>CBO</sub>	60±10	V
Collector-emitter voltage	V <sub>CEO</sub>	60±10	V
Emitter-base voltage	V <sub>EBO</sub>	5	V
Collector current	I <sub>C</sub>	500	mA
Collector current (P <sub>W</sub> =10ms, single pulse)	I <sub>CP</sub>	1	А
Power dissipation	P <sub>D</sub> <sup>*1</sup>	1.25 (Total) <sup>*2</sup>	W
Junction temperature	Tj	150	°C
Range of storage temperature	T <sub>stg</sub>	-55 to +150	°C

### •Electrical characteristics(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-base breakdown voltage	$BV_{CBO}$	I <sub>C</sub> = 50μA	50	-	70	V
Collector-emitter breakdown voltage	$BV_{CEO}$	I <sub>C</sub> = 50μA	50	-	70	V
Emitter-base breakdown voltage	$BV_{EBO}$	I <sub>E</sub> = 720μA	5	-	-	V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = 40V	-	-	0.5	μA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = 4V	300	-	580	μA
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> / I <sub>B</sub> = 100mA / 1mA	-	0.1	0.3	V
DC current gain	h <sub>FE</sub>	$V_{CE}$ = 5V, $I_{C}$ = 0.2A	500	-	-	-
Emitter-base resistance	R	-	7	10	13	kΩ

\*1 Mounted on a ceramic substrate.

\*2 0.9W per element must not be exceeded.

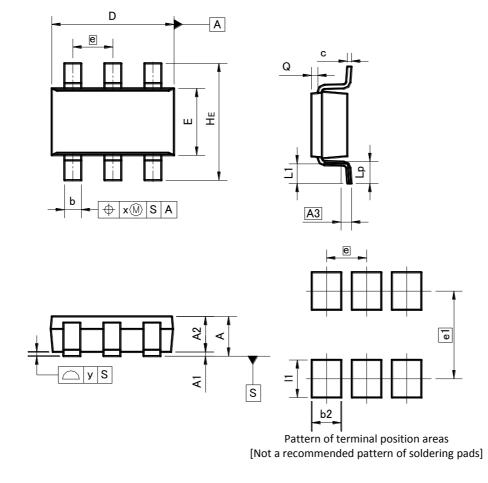
#### Fig.2 Grounded emitter output characteristics Fig.1 Grounded emitter propagation characteristics I<sub>B</sub>= 1.0mA\_0.9mA\_0.8mA 1000 500 0.7mA $V_{CE} = 5V$ Ta= 25⁰C COLLECTOR CURRENT : I<sub>C</sub> [mA] 0.6mA COLLECTOR CURRENT : I<sub>C</sub> [mA] 400 0.5mA 100 0.4mA 300 10 0.3mA 100°C Ta= 200 25⁰C -40°C 0.2mA 1 100 0.1mA 0.1 0 0mA 0 0.5 1 1.5 2 0 2 4 6 8 10 BASE TO EMITTER VOLTAGE : V<sub>BE</sub> [V] COLLECTOR TO EMITTER VOLTAGE : V<sub>CE</sub> [V] Fig.3 DC Current gain Fig.4 Collector-emitter saturation voltage vs. Collector Current vs. Collector Current 10000 10 $V_{CE} = 5V$ $I_{C}/I_{B}=10$ COLLECTOR SATURATION VOLTAGE : V<sub>CE(sat)</sub> [V] DC CURRENT GAIN : hre 1000 Ta= 100°C 25°C 1 Ta= 100°C -40°C 25⁰C 100 -40°C 0.1 10 0.01 1 0.1 10 100 1000 10 100 1000 1 1 COLLECTOR CURRENT : I<sub>C</sub> [mA] COLLECTOR CURRENT : I<sub>C</sub> [mA]

#### •Electrical characteristic curves(Ta = 25°C)

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#### •Dimensions (Unit : mm)

TSMT6



DIM	MILIM	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
А	-	1.00	-	0.039	
A1	0.00	0.10	0.000	0.004	
A2	0.75	0.95	0.030	0.037	
A3	0.2	25	0.0	10	
b	0.35	0.50	0.014	0.020	
с	0.10	0.26	0.004	0.010	
D	2.80	3.00	0.110	0.118	
E	1.50	1.80	0.059	0.071	
е	0.95		0.0	37	
HE	2.60	3.00	0.102	0.118	
L1	0.30	0.60	0.012	0.024	
Lp	0.40	0.70	0.016	0.028	
Q	0.05	0.25	0.002	0.010	
x	_	0.20	_	0.008	
У	_	0.10	_	0.004	

DIM	MILIM	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
b2		0.70	-	0.028	
e1	2.10		0.0	83	
1	_	0.90	_	0.035	

Dimension in mm / inches

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